










	<h2 style="color: red;">DMN3115UDM-7</h2>	
	<b>Hersteller-Teilenummer:</b>	<a href="#">DMN3115UDM-7</a>
	<b>Hersteller / Marke:</b>	<a href="#">Diodes Incorporated</a>
	<b>Teil der Beschreibung:</b>	MOSFET N-CH 30V 3.2A SOT-26
<b>Datenblätter:</b>	 <a href="#">DMN3115UDM-7.pdf</a>	
<b>RoHs Status:</b>	Bleifrei / RoHS-konform	
<b>Lagerzustand:</b>	New original, 89143 pcs Stock Available.	
<b>Liefern von:</b>	Hong Kong	
<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

### Spezifikationen

Teilenummer	<a href="#">DMN3115UDM-7</a>
Hersteller	<a href="#">Diodes Incorporated</a>
Beschreibung	MOSFET N-CH 30V 3.2A SOT-26
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	89143 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SOT-23-6
Supplier Device-Gehäuse	SOT-26
Verlustleistung (max)	900mW (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	3.2A (Ta)
Rds On (Max) @ Id, Vgs	60 mOhm @ 6A, 4.5V
VGS (th) (Max) @ Id	1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	-
Eingabekapazität (Ciss) (Max) @ Vds	476pF @ 15V
Antriebsspannung (Max Rds On, Min Rds On)	1.5V, 4.5V
Vgs (Max)	±8V
Verpackung	Original-Reel®

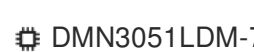
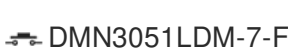

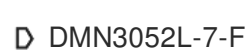

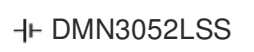
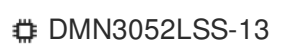
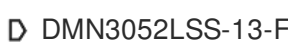
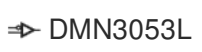

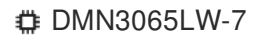
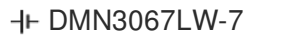
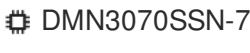
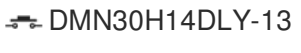
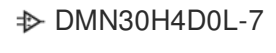
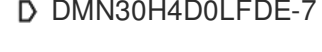
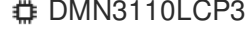
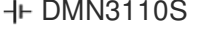
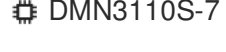
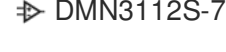
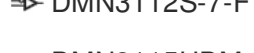
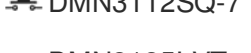
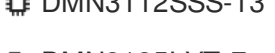
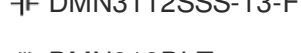
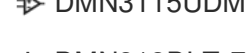
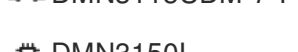
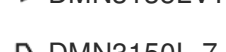
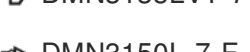
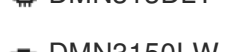
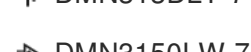





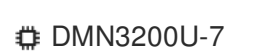
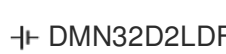
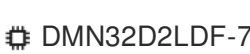
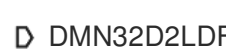

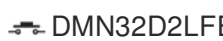
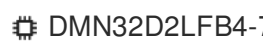








DMN3115UDM-7 ist neu im Original, Suche DMN3115UDM-7 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie DMN3115UDM-7 Diodes Incorporated mit Garantie und Vertrauen. Anfrage DMN3115UDM-7: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>DMN313DLT</b> D DMN313DLT D</p>	 <p><b>DMN3115UDM-7-F</b> DIODES DMN3115UDM-7-F DIODES</p>	 <p><b>DMN3112SQ-7</b> T DMN3112SQ-7 T</p>	 <p><b>DMN3112SSS-13</b> Diodes Incorporated MOSFET N-CH 30V 6A 8SOP</p>
 <p><b>DMN3135LVT-7</b> Diodes Incorporated MOSFET 2N-CH 30V 3.5A TSOT26</p>	 <p><b>DMN313DLT-7</b> Diodes Incorporated MOSFET N-CH 30V 0.27A SOT523</p>	 <p><b>DMN3112SSS-13-F</b> DIODES DMN3112SSS-13-F DIODES</p>	 <p><b>DMN3112S-7-F</b> DIODES DMN3112S-7-F DIODES</p>

### heiße Teile

Mehr

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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